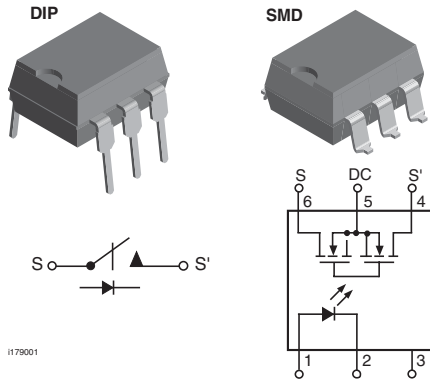


1 Form A Solid State Relay



DESCRIPTION

The LH1546 is robust, ideal for telecom and ground fault applications. It is a SPST normally open switch (1 form A) that replaces electromechanical relays in many applications. It is constructed using a GaAlAs LED for actuation control and an integrated monolithic die for the switch output. The die, fabricated in a high-voltage dielectrically isolated technology, is comprised of a photodiode array, switch control circuitry and MOSFET switches. In addition, it employs current-limiting circuitry which meets FCC 68.302 and other regulatory voltage surge requirements when overvoltage protection is provided.

FEATURES

- Current limit protection
- Isolation test voltage 5300 V_{RMS}
- Typical R_{ON} 28 Ω
- Load voltage 350 V
- Load current 120 mA
- High surge capability
- Clean bounce free switching
- Low power consumption
- High reliability monolithic receptor
- SMD lead available on tape and reel
- Equivalent to CP Clare LCA110
- Lead (Pb)-free component
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC



RoHS
COMPLIANT

APPLICATIONS

- General telecom switching
 - On/off hook control
 - Ring delay
 - Dial pulse
 - Ground start
 - Ground fault protection
- Instrumentation
- Industrial controls

Note

See "solid state relays" (application note 56)

AGENCY APPROVALS

UL1577: file no. E52744 system code H or J, double protection
 CSA: certification no. 093751
 BSI/BABT: certification no. 7980
 FIMKO: approval

ORDER INFORMATION

PART	REMARKS	PACKAGE
LH1546AAB	Tubes	SMD-6
LH1546AABTR	Tape and reel	SMD-6
LH1546AT	Tubes	DIP-6

ABSOLUTE MAXIMUM RATINGS ⁽¹⁾				
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT
SSR				
LED continuous forward current		I_F	50	mA
LED reverse voltage	$I_R \leq 10 \mu A$	V_R	8.0	V
DC or peak AC load voltage	$I_L \leq 50 \mu A$	V_L	350	V
Continuous DC load current at 25 °C, bidirectional		I_L	120	mA
Continuous DC load current at 25 °C, unidirectional		I_L	200	mA
Ambient temperature range		T_{amb}	- 40 to + 85	°C
Storage temperature range		T_{stg}	- 40 to + 150	°C
Soldering temperature ⁽²⁾	$t = 10 \text{ s max.}$	T_{sld}	260	°C
Isolation test voltage	for 1.0 s	V_{IO}	5300	V_{RMS}
Isolation resistance	$V_{IO} = 500 \text{ V}, T_{amb} = 25 \text{ °C}$	R_{IO}	$\geq 10^{12}$	Ω
	$V_{IO} = 500 \text{ V}, T_{amb} = 100 \text{ °C}$	R_{IO}	$\geq 10^{11}$	Ω
SSR output power dissipation (continuous)		P_{diss}	550	mW

Notes

⁽¹⁾ $T_{amb} = 25 \text{ °C}$, unless otherwise specified.

Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute maximum ratings for extended periods of the time can adversely affect reliability.

⁽²⁾ Refer to reflow profile for soldering conditions for surface mounted devices (SMD). Refer to wave profile for soldering conditions for through hole devices (DIP).

ELECTRICAL CHARACTERISTICS						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
INPUT						
LED forward current, switch turn-on	$I_L = 100 \text{ mA}, t = 10 \text{ ms}$	I_{Fon}		1.1	2.0	mA
LED forward current, switch turn-off	$V_L = \pm 350 \text{ V}$	I_{Foff}	0.2	1.0		mA
LED forward voltage	$I_F = 10 \text{ mA}$	V_F	1.15	1.26	1.45	V
OUTPUT						
On-resistance, AC/DC: pin 4 ($\pm$) to 6 ($\pm$)	$I_F = 5.0 \text{ mA}, I_L = 50 \text{ mA}$	R_{ON}		28	35	Ω
On-resistance, DC: pin 4, 6 (+) to 5 (-)	$I_F = 5.0 \text{ mA}, I_L = 50 \text{ mA}$	R_{ON}		7.0	10	Ω
Off-resistance	$I_F = 0 \text{ mA}, V_L = \pm 100 \text{ V}$	R_{OFF}	0.5	300		$G\Omega$
Current limit AC/DC	$I_F = 5.0 \text{ mA}, t = 5.0 \text{ ms}, V_L = 6.0 \text{ V}$	I_{LMT}	170	210	250	mA
Off-state leakage current	$I_F = 0 \text{ mA}, V_L = \pm 100 \text{ V}$	I_O		0.35	200	nA
	$I_F = 0 \text{ mA}, V_L = \pm 350 \text{ V}$	I_O		0.096	1.0	μA
Output capacitance pin 4 to 6	$I_F = 0 \text{ mA}, V_L = 1.0 \text{ V}$	C_O		18		pF
	$I_F = 0 \text{ mA}, V_L = 50 \text{ V}$	C_O		6.7		pF
Switch offset	$I_F = 5.0 \text{ mA}$	V_{OS}		0.3		μV
TRANSFER						
Capacitance (input to output)	$V_{ISO} = 1.0 \text{ V}$	C_{IO}		0.67		pF
Turn-on time	$I_F = 5.0 \text{ mA}, I_L = 50 \text{ mA}$	t_{on}		1.14	3.0	ms
Turn-off time	$I_F = 5.0 \text{ mA}, I_L = 50 \text{ mA}$	t_{off}		0.71	3.0	ms

Note

$T_{amb} = 25 \text{ °C}$, unless otherwise specified.

Minimum and maximum values are testing requirements. Typical values are characteristics of the device and are the result of engineering evaluations. Typical values are for information only and are not part of the testing requirements.



TYPICAL CHARACTERISTICS

$T_{amb} = 25^{\circ}\text{C}$, unless otherwise specified

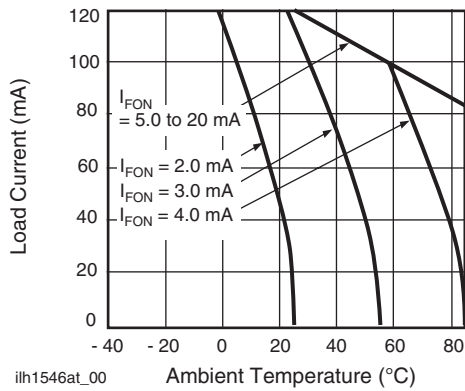


Fig. 1 - Recommended Operating Conditions

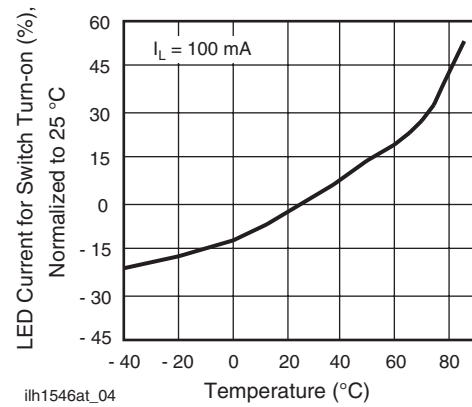


Fig. 4 - LED Current for Switch Turn-on vs. Temperature

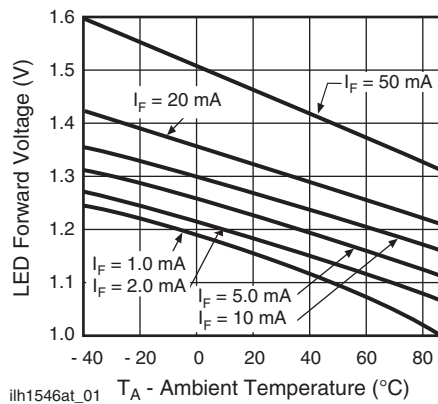


Fig. 2 - LED Voltage vs. Temperature

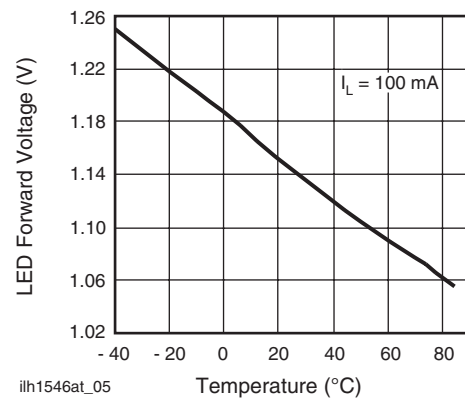


Fig. 5 - LED Dropout Voltage vs. Temperature

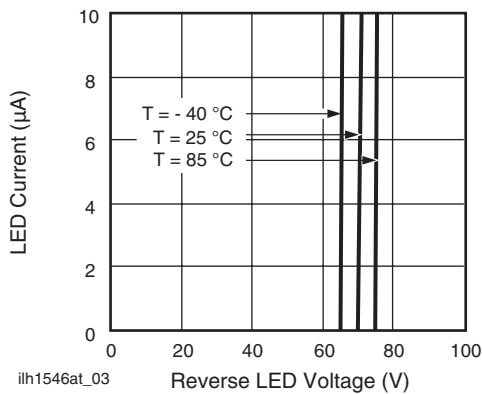


Fig. 3 - LED Reverse Current vs. LED Reverse Voltage

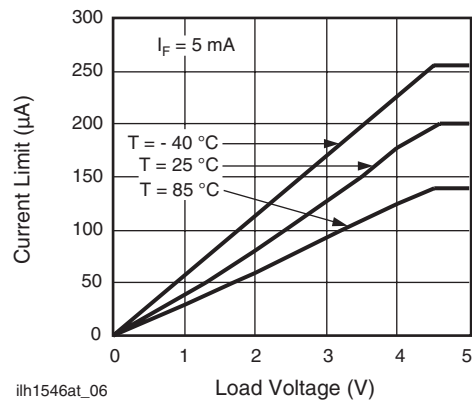
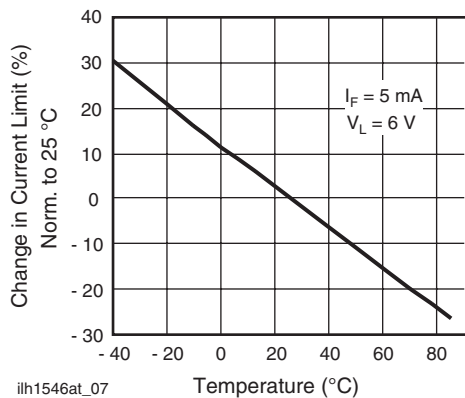
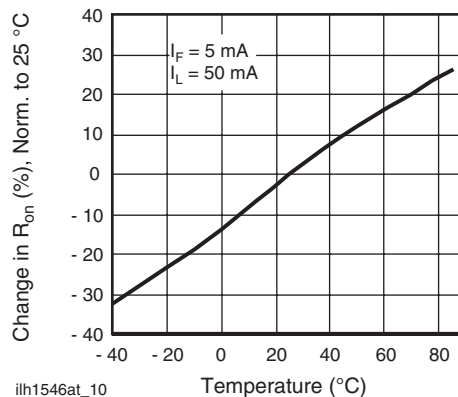


Fig. 6 - Load Current vs. Load Voltage



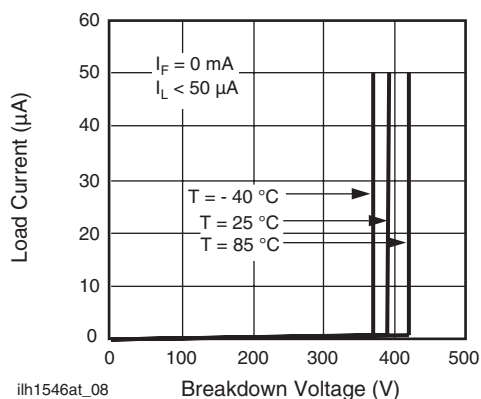
ilh1546at_07

Fig. 7 - Current Limit vs. Temperature



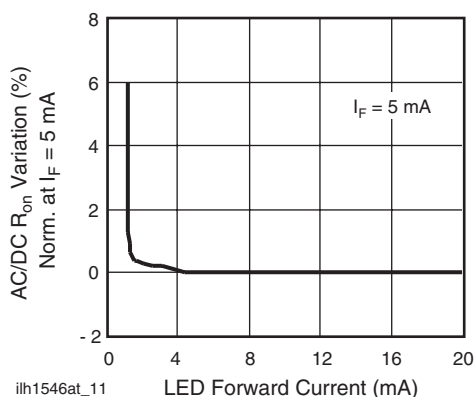
ilh1546at_10

Fig. 10 - On-resistance vs. Temperature



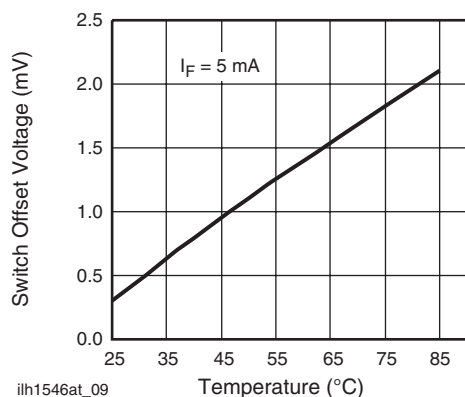
ilh1546at_08

Fig. 8 - Switch Breakdown Voltage vs. Load Current



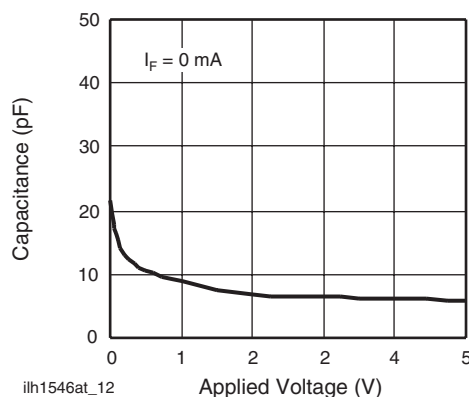
ilh1546at_11

Fig. 11 - Variation in On-resistance vs. LED Current



ilh1546at_09

Fig. 9 - Switch Offset Voltage vs. LED Current



ilh1546at_12

Fig. 12 - Switch Capacitance vs. Applied Voltage

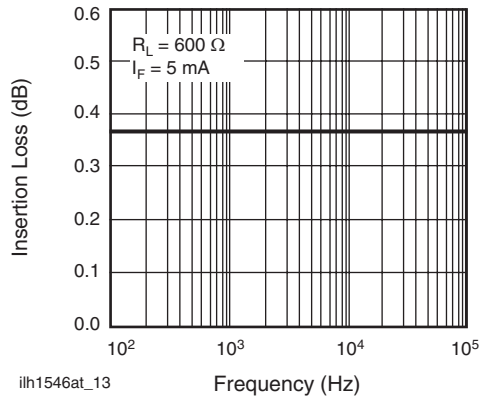


Fig. 13 - Insertion Loss vs. Frequency

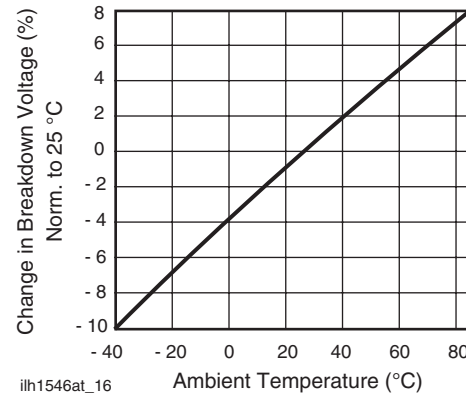


Fig. 16 - Switch Breakdown Voltage vs. Temperature

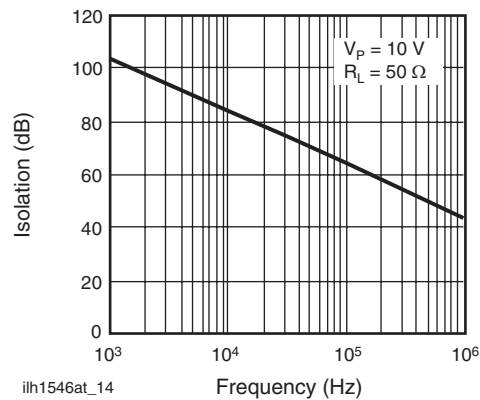


Fig. 14 - Output Isolation

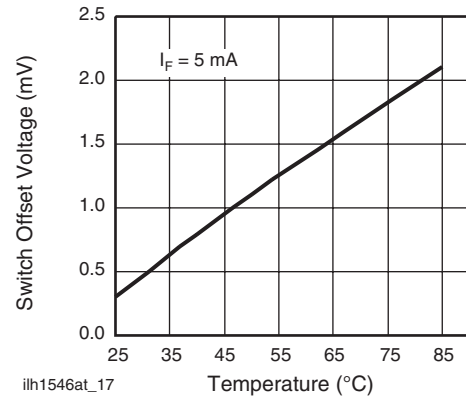


Fig. 17 - Switch Offset Voltage vs. Temperature

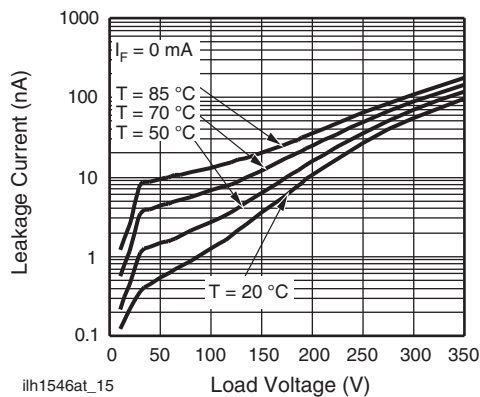


Fig. 15 - Leakage Current vs. Applied Voltage at Elevated Temperatures

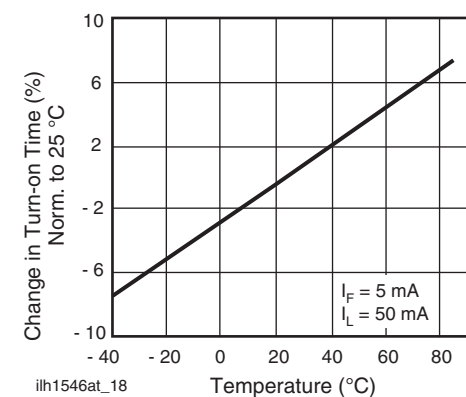


Fig. 18 - Turn-on Time vs. Temperature

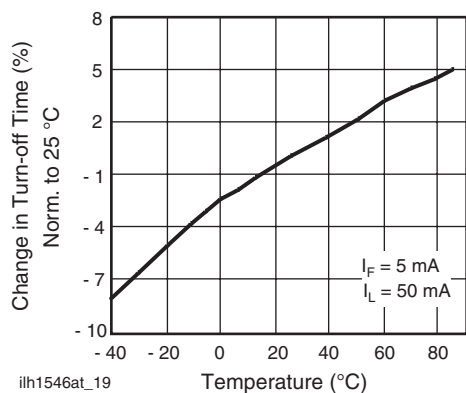


Fig. 19 - Turn-off Time vs. Temperature

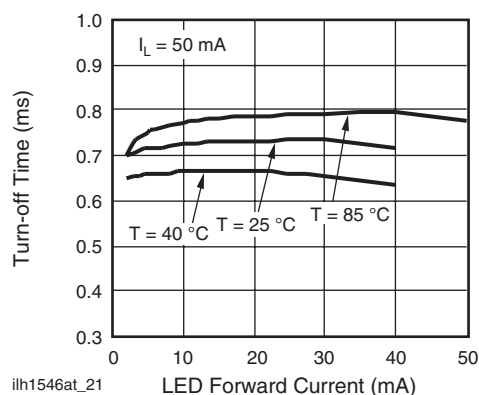


Fig. 21 - Turn-off Time vs. LED Current

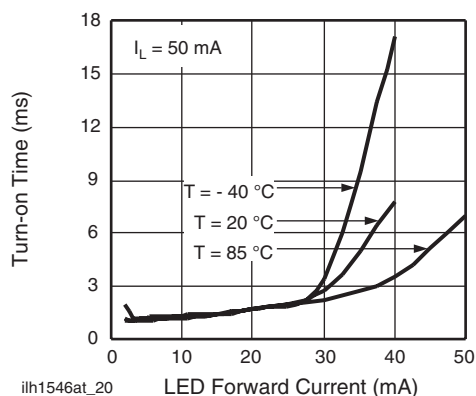
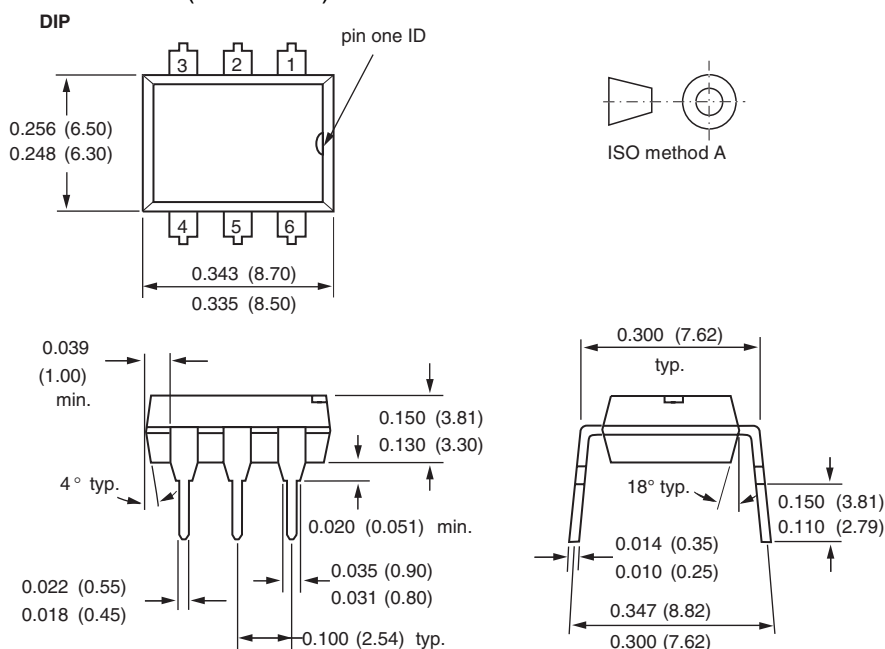


Fig. 20 - Turn-on Time vs. LED Current

PACKAGE DIMENSIONS in inches (millimeters)



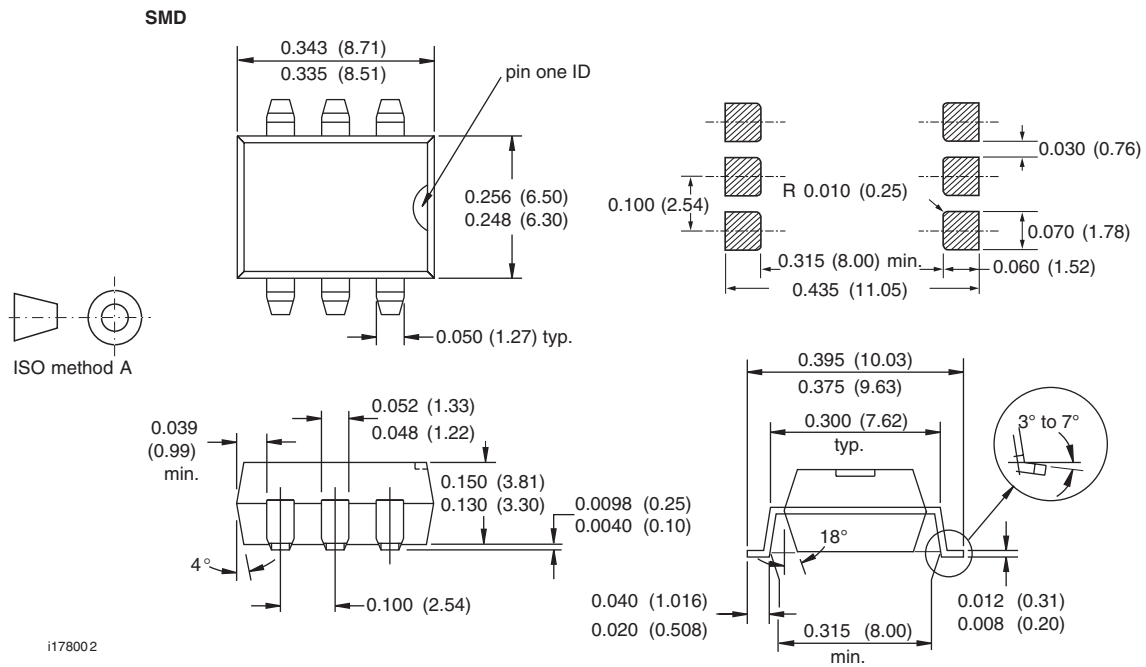


LH1546AT/LH1546AAB/LH1546AABTR

1 Form A Solid State Relay

Vishay Semiconductors

PACKAGE DIMENSIONS in inches (millimeters)



**OZONE DEPLETING SUBSTANCES POLICY STATEMENT**

It is the policy of Vishay Semiconductor GmbH to

1. Meet all present and future national and international statutory requirements.
2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

Vishay Semiconductor GmbH has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively.
2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA.
3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

Vishay Semiconductor GmbH can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

We reserve the right to make changes to improve technical design
and may do so without further notice.

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